

SKiiP 642 GB 120 - 208 CTV

Absolute Maximum Ratings		Values	Units
Symbol	Conditions¹⁾		
IGBT & Inverse Diode			
V_{CES}		1200	V
V_{CC} ⁹⁾	Operating DC link voltage	900	V
I_C	$T_{heatsink} = 25^\circ\text{C}$	600	A
T_j ³⁾	IGBT & Diode	- 40 ... + 150	
V_{isol} ⁴⁾	AC, 1 min.	3000 ⁵⁾	V
I_F	$T_{heatsink} = 25^\circ\text{C}$	600	A
I_{FM}	$T_{heatsink} = 25^\circ\text{C}; t_p < 1\text{ ms}$	1200	A
I_{FSM}	$t_p = 10\text{ ms}; \sin.; T_j = 150^\circ\text{C}$	4300	A
I^2_t (Diode)	$t_d = 10\text{ ms}; T_i = 150^\circ\text{C}$	93	kA^2s

Characteristics

Symbol	Conditions ¹⁾	min.	typ.	max.	Units
$V_{(BR)CES}$	Driver without power supply	$\geq V_{CES}$	—	—	V
I_{CES}	$V_{GE} = 0 \quad T_j = 25 \text{ }^\circ\text{C}$	—	0,6	—	mA
	$V_{CE} = V_{CES} \quad T_j = 125 \text{ }^\circ\text{C}$	—	30	—	mA
V_{CEsat}	$I_C = 450 \text{ A} \quad T_j = 25 \text{ (125) }^\circ\text{C}$	—	2,6(3)	—	V
V_{CEsat}	$I_C = 600 \text{ A} \quad T_j = 25 \text{ (125) }^\circ\text{C}$	—	3,0(3,6)	—	V
C_{CHC}	per SKiiPPACK AC side	—	1,6	—	nF
L_{CE}	Top (Bottom)	—	7,5	—	nH
$t_{d(on)}$	$I_C = 600 \text{ A}$ $T_j = 125 \text{ }^\circ\text{C}$ inductive load	—	150	—	ns
$t_{d(on)Driver}$		—	1,0	—	μs
t_r		—	100	—	ns
$t_{d(off)}$		—	0,6	—	μs
$t_{d(off)Driver}$		—	1,0	—	μs
t_f		—	80	—	ns
$E_{on} + E_{off}$		$V_{CC} = 600 \text{ V} / 900 \text{ V}$	—	180 / 294	mJ
Inverse Diode ²⁾					
$V_F = V_{EC}$	$I_F = 450 \text{ A} \quad T_j = 25 \text{ (125) }^\circ\text{C}$	—	1,9(1,8)	—	V
	$I_F = 600 \text{ A} \quad T_j = 25 \text{ (125) }^\circ\text{C}$	—	2,1(2,05)	—	V
$E_{on} + E_{off}$	$I_F = 600 \text{ A}; T_j = 125 \text{ }^\circ\text{C}$	—	24	—	mJ
$ V_{CE}(t) $ ($t = T_j - t_{d(on)}$ ²⁾)					

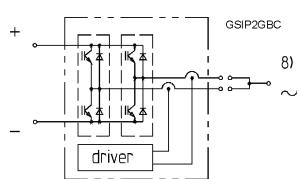
SKIPPACK®

SK integrated intelligent Power PACK halfbridge

**SKiiP 642 GB 120
+ Driver 208 CTV^{7,13)}**

Preliminary Data

Case S2



Features

- Low thermal impedance
 - Optimal thermal management with integrated heatsink
 - Pressure contact technology with increased power cycling capability, compact design
 - Low stray inductance
 - High power, small losses
 - Overtemp. protection
 - Short circuit protection, due to evaluation of current sensor signals
 - Isolated power supply

1) $T_{\text{heatsink}} = 25 \text{ }^{\circ}\text{C}$, unless otherwise specified

2) CAL = Controlled Axial Lifetime Technology (soft and fast)

3) without driver

4) Driver input to DC link/AC output or DC link/AC output to heatsink

5) 4 kV (AC; on request)
6)

8) other heatsink on request

- ✓ C - integrated current sensors
- ✓ T - Temperature protection
- ✓ V_D 15 V or 24 V power supply

8) AC connection bushings

- > AC connection busbars must be connected by user copper

connected by user, copper bus-bars available on request

- 12) with SR-DC link (low inductance)
- 12) thermal reference for R_{thjh} ; R_{thha}
- 13) options available for driver

- U - DC-link voltage sense
- E - Fiber optic connector

IGBT / Inverse Diod

V_{TO}	$T_j = 125^\circ C$	–	1,4 / 0,9	–	V
I_T	$T_j = 125^\circ C$	–	4 / 2	–	$m\Omega$
Thermal Characteristics					
R_{thjh}	per IGBT	–	0,045	–	K/W
R_{thjh}	per diode	–	0,12	–	K/W
$T_{tp}^{(12)}$	Over temperature protection	110	115	120	°C
$R_{thba}^{(6)}$	P16/200 F: $v_{air} = 293 \text{ m}^3 / \text{h}$	–	0,044	–	K/W

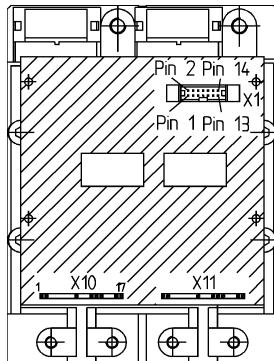
SKiiPPACK protection

TRIP 1 ACK protection					
ITRIPSC	Short circuit protection	735	750	765	A
TTRIP	Overtemperature protection	110	115	120	°C
UDCTRIP ¹³⁾	Udc-protection	900	920	940	V

Mechanical Data

Mdc	for DC terminals, SI Units	4	-	6	Nm
Mac	for AC terminals, SI Units	8	-	10	Nm
Case			S2		

SKiiPPACK®
SK integrated intelligent Power PACK
halfbridge
SKiiP 642 GB 120
+ Driver 208 CTV^{3,5)}
Preliminary Driver Data



Features

- CMOS compatible inputs
- Short circuit protection by evaluation of current sensor signals
- Drive interlock top/bottom
- Isolation by transformers
- Supply undervoltage protection
- Overtemperature protection
- Fiber optic connector (option)
- Udc-monitoring (option)

- 24 V - power supply
- Open collector output, external pull-up resistor necessary
- C - integrated current sensors
- T - Temperature protection
- V - 15 V or 24 V power supply
- 4 kVAC (on request)
- options available for driver
- U - DC-link voltage sense
- F - Fiber optic connectors
- IAC - AC-current per phase

SKiiP 642 GB 120 - 208 CTV
Driver for Halfbridge

Symbol	Conditions	Values	Units	remark
V _{S1}	supply voltage primary	18	V	pin 8 / 9
V _{S2} ¹⁾	supply voltage primary	30	V	pin 6 / 7
I _{outmax}	output peak current max.	± 10	A	
I _{outAV}	output average current	± 100	mA	
f _{swmax}	switching frequency max.	20	kHz	
dV/dt	rate of rise and fall of voltage (secondary to primary side)	75	kV/μs	
V _{isol IO} ⁴⁾	Isol. test volt. IN/OUT (RMS; 1 min)	3	kV~	
V _{isol 12}	Isol. test volt. output 1 - output 2	1,5	kV=	
T _{op} , T _{stg}	operating / stor. temperature	- 25 ... + 85	°C	

Symbol	Conditions	Values	Units	remark
V _{S1}	supply voltage primary	15,0 ± 4 %	V	pin 8 / 9
V _{S2} ¹⁾	supply voltage primary	24,0 +25%/-15%	V	pin 6 / 7
V _{UVS}	supply voltage monitoring	13 / 19,5	V	15 V / 24 V
I _{S01}	sup.current pr.side (standby)	210	mA	15 V supply
I _{S02} ¹⁾	sup.current pr.side (standby)	160	mA	24 V supply
I _{S1}	sup. current pr.side (max) at f _{swmax}	640 + 1,3 · I _{AC} ⁶⁾	mA	15 V supply
I _{S2} ¹⁾	sup. current pr.side (max) at f _{swmax}	1000 460 + 1,3 · I _{AC} ⁶⁾ 1350	mA	24 V supply
V _{IT+}	input thresh. volt. (high) min.	11,2	V	
V _{IT-}	input thresh. volt. (low) max.	5,4	V	
V _{GE(on)}	turn-on output gate voltage	15	V	
V _{GE(off)}	turn-off output gate voltage	- 8	V	
t _{d(on)}	propagation delay time on	1,0	μs	typ.
t _{d(off)}	propagation delay time off	1,0	μs	typ.
t _{TD}	dead time of interlock	3	μs	typ.
V _{OL} ²⁾	logic low output voltage	< 600 max. 30	mV	15 mA
V _{OH} ²⁾	logic high output voltage	V		
t _{pdon-error}	propag. delay time-on error	1	μs	typ.
t _{p RESET}	min. pulse width error	8	μs	
T _{TRIP}	max. temperature	115 ± 5	°C	
I _{A0max}	max. output current	± 5	mA	pin 12/14
U _{TRIPSC}	overcurrent trip level	10	V	10 V = 125% I _C
U _{DCTRIP}	overvoltage trip level	9	V	9 V = 900 V; using option "U"